## NSN 5961-01-369-4900

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-369-4900 **Inclosure Material:** Plastic **Overall Length:** 0.300 inches **Terminal Length:** 1.000 inches **Overall Diameter:** 0.125 inches **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 3.7 breakdown voltage, dc and 4.09 breakdown voltage, dc **Current Rating Per Characteristic:** 64.00 milliamperes emitter current, dc **Power Rating Per Characteristic:** 1000.0 milliwatts any acceptable preset **Maximum Operating Tempurature Per Measurement Point:** 347.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig:

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